Ordering number : ENA1836B

PCP1208

Bipolar Transistor
200V, 0.7A Low V_{CE}(sat) NPN Single PCP

ON Semiconductor®

http://onsemi.com

Features

- V_{CEO}=200V, I_C=0.7A
- High allowable power dissipation
- Halogen free compliance
- Low collector-to-emitter saturation voltage V_{CE}(sat)=0.115V(typ.)@I_C=0.35A
- High-speed switching t_f=70ns(typ.)@I_C=0.3A

Specifications

Absolute Maximum Ratings at Ta=25°C

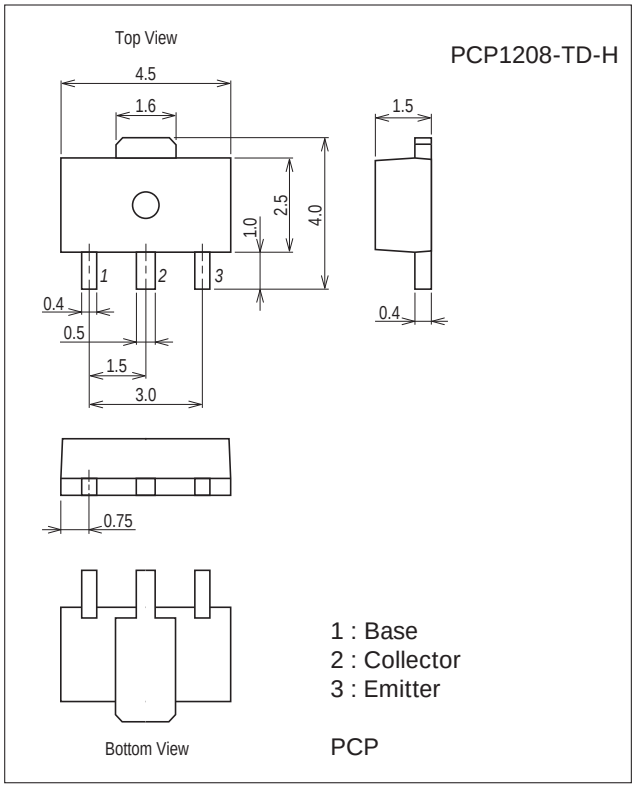
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		220	V
Collector-to-Emitter Voltage	V_{CEO}		200	V
Emitter-to-Base Voltage	V_{EBO}		8	V
Collector Current	I_C		0.7	A
Collector Current (Pulse)	I_{CP}		2	A
Base Current	I_B		140	mA
Collector Dissipation	P_C	When mounted on ceramic substrate (450mm²×0.8mm)	1.3	W
		Tc=25°C	3.5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

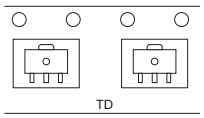
7008B-003



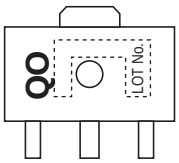
Ordering & Package Information

Device	Package	Shipping	note
PCP1208-TD-H	PCP (SC-62, SOT-89, TO-243)	1,000 pcs./reel	Pb Free and Halogen Free

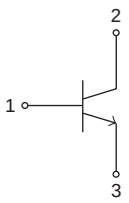
Packing Type: TD



Marking



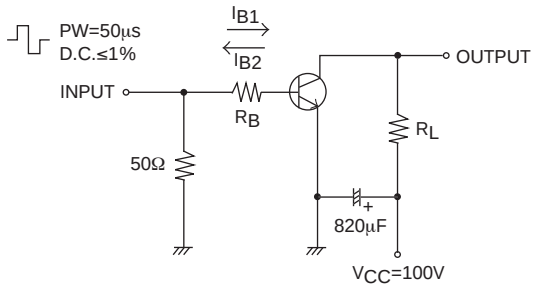
Electrical Connection



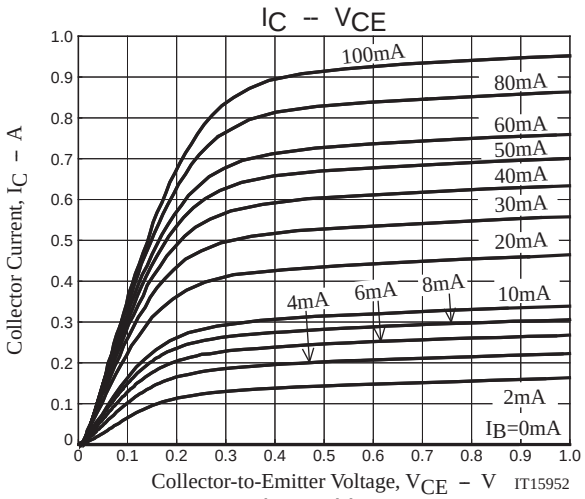
Electrical Characteristics at Ta=25°C

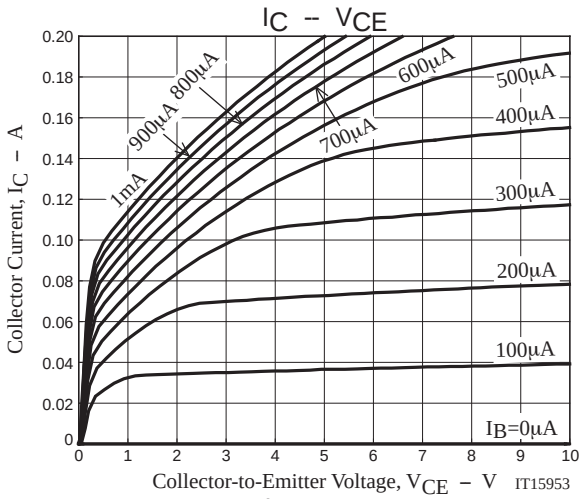
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	V_{CB}=100V, I_E=0A			1	μA
Emitter Cutoff Current	I_{EBO}	V_{EB}=4V, I_C=0A			1	μA
DC Current Gain	h_{FE}	V_{CE}=5V, I_C=100mA	200		560	
Gain-Bandwidth Product	f_T	V_{CE}=10V, I_C=100mA		120		MHz
Output Capacitance	Cob	V_{CB}=10V, f=1MHz		9		pF
Collector-to-Emitter Saturation Voltage	V_{CE}(sat)	I_C=0.35A, I_B=35mA		115	200	mV
Base-to-Emitter Saturation Voltage	V_{BE}(sat)	I_C=0.35A, I_B=35mA		0.82	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	I_C=10μA, I_E=0A	220			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C=1mA, R_{BE}=∞	200			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	I_E=10μA, I_C=0A	8			V
Turn-On Time	t_{on}	See specified Test Circuit.		50		ns
Storage Time	t_{stg}			2		μs
Fall Time	t_f			70		ns

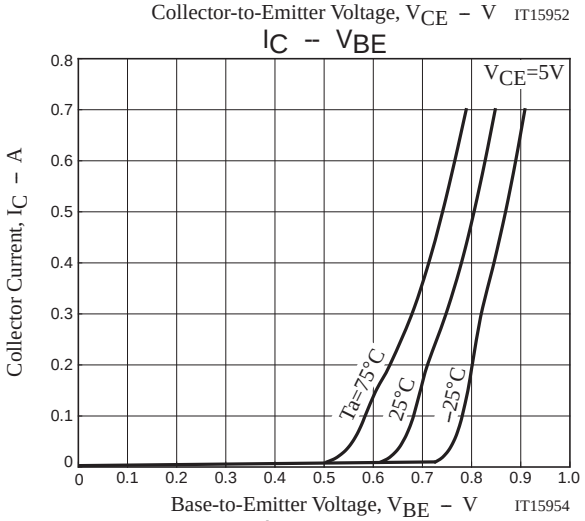
Switching Time Test Circuit

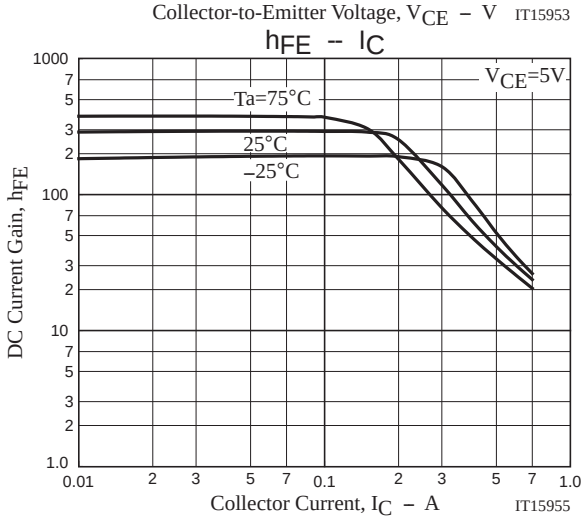


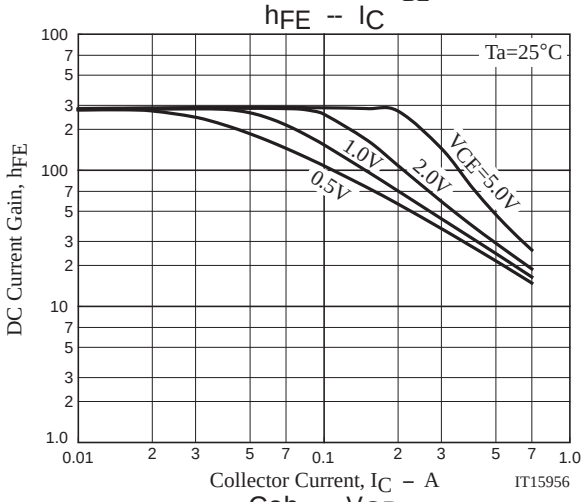
I_C=10I_{B1}= −10I_{B2}=0.3A

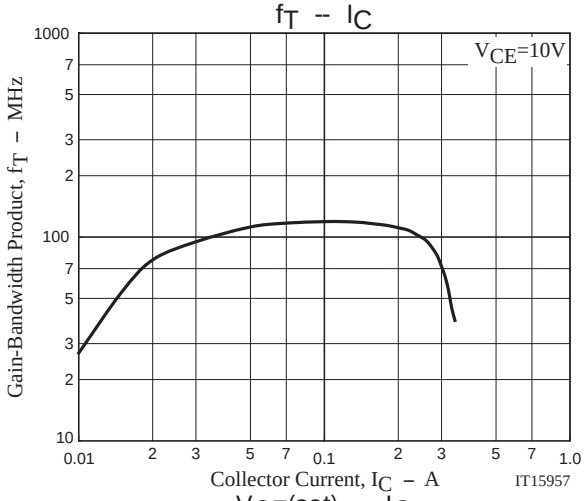

IC – VCE
Collector Current, IC – A
Collector-to-Emitter Voltage, VCE – V
IT15952
100mA
80mA
60mA
50mA
40mA
30mA
20mA
10mA
8mA
6mA
4mA
2mA
IB=0mA

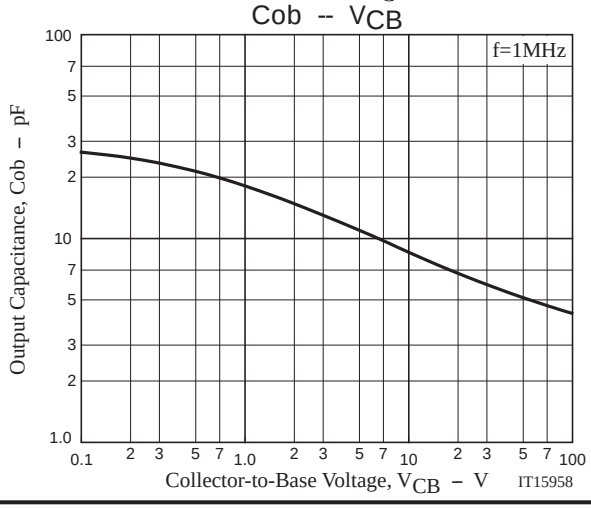

IC – VCE
Collector Current, IC – A
Collector-to-Emitter Voltage, VCE – V
IT15953
1mA
900µA
800µA
700µA
600µA
500µA
400µA
300µA
200µA
100µA
IB=0µA

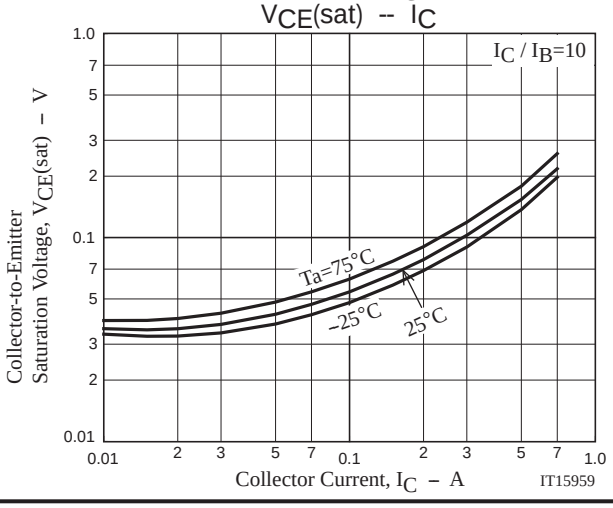

IC – VBE
Collector Current, IC – A
Base-to-Emitter Voltage, VBE – V
IT15954
VCE=5V
Ta=75°C
25°C
–25°C

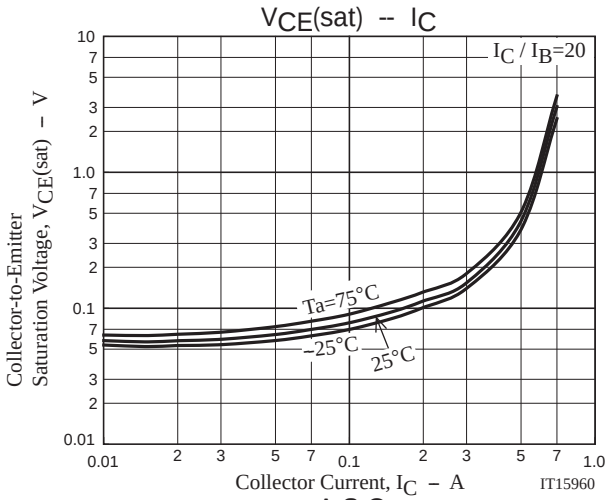

hFE – IC
DC Current Gain, hFE
Collector Current, IC – A
IT15955
VCE=5V
Ta=75°C
25°C
–25°C

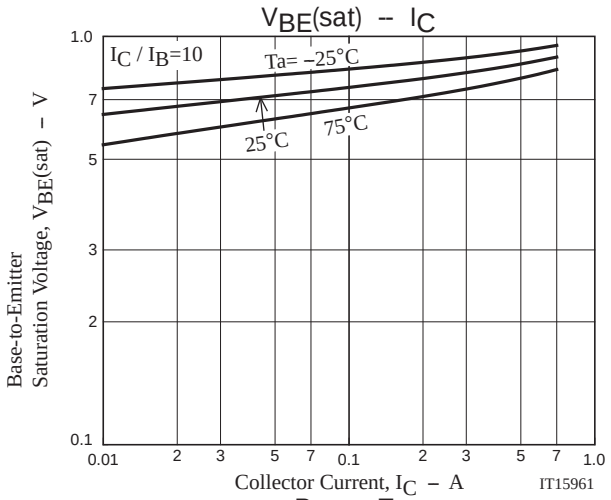

hFE – IC
DC Current Gain, hFE
Collector Current, IC – A
IT15956
Ta=25°C
VCE=5.0V
2.0V
1.0V
0.5V

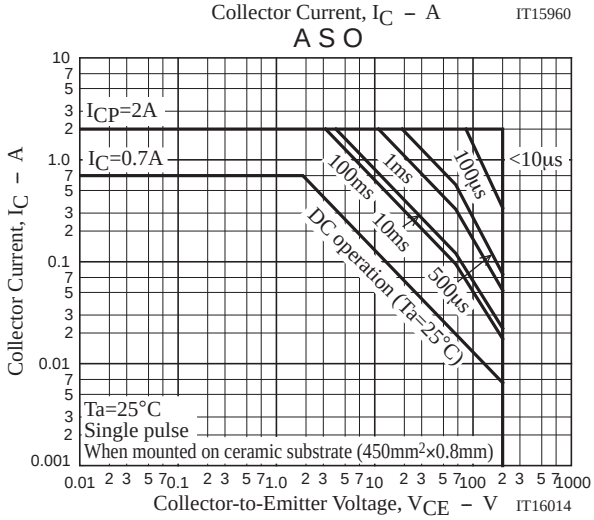

fT – IC
Gain-Bandwidth Product, fT – MHz
Collector Current, IC – A
IT15957
VCE=10V

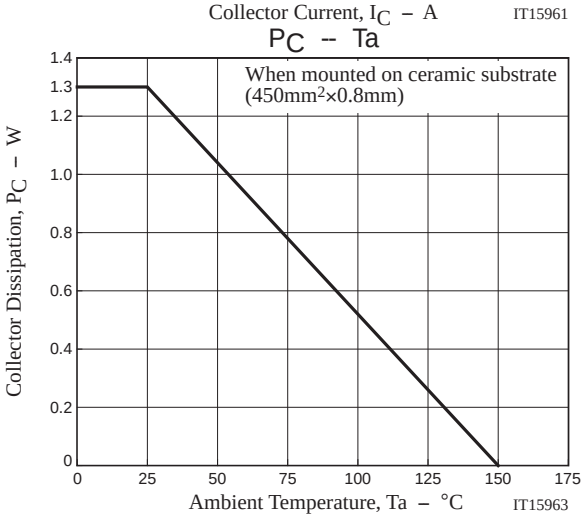

Cob – VCB
Output Capacitance, Cob – pF
Collector-to-Base Voltage, VCB – V
IT15958
f=1MHz


VCE(sat) – IC
Collector-to-Emitter Saturation Voltage, VCE(sat) – V
Collector Current, IC – A
IT15959
IC / IB=10
Ta=75°C
–25°C
25°C


VCE(sat) -- IC
IC / IB=20
Ta=75°C
–25°C
25°C
Collector-to-Emitter Saturation Voltage, VCE(sat) – V
Collector Current, IC – A
IT15960


VBE(sat) -- IC
IC / IB=10
Ta= –25°C
25°C
75°C
Base-to-Emitter Saturation Voltage, VBE(sat) – V
Collector Current, IC – A
IT15961


A S O
ICP=2A
IC=0.7A
100ms
1ms
10ms
100µs
<10µs
500µs
DC operation (Ta=25°C)
Ta=25°C
Single pulse
When mounted on ceramic substrate (450mm2×0.8mm)
Collector Current, IC – A
Collector-to-Emitter Voltage, VCE – V
IT16014


PC – Ta
When mounted on ceramic substrate (450mm2×0.8mm)
Collector Dissipation, PC – W
Ambient Temperature, Ta – °C
IT15963

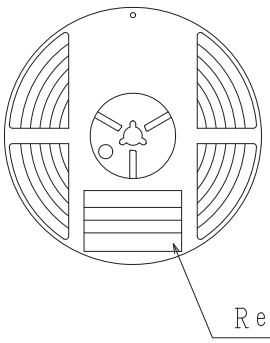
Bag Packing Specification

PCP1208-TD-H

1. Packing Format

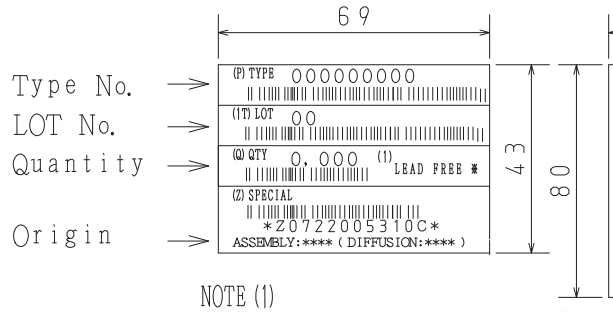
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
PCP	PCP	1,000	4,000	24,000	4 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



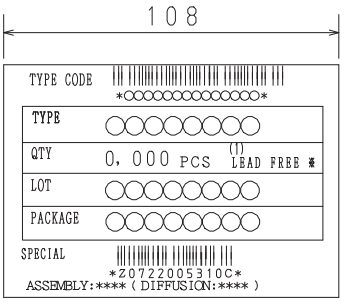
Reel label

Reel label, Inner box label (unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.

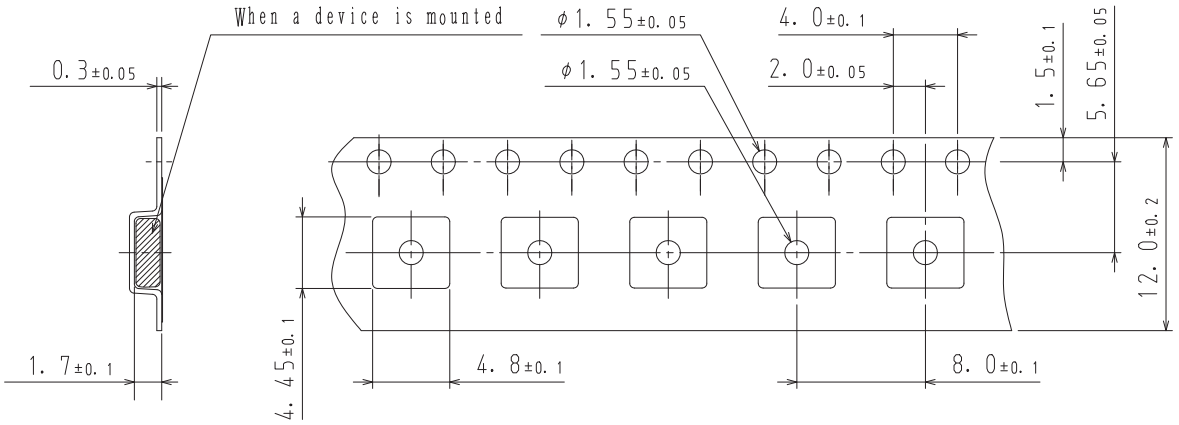


NOTE (1)
The LEAD FREE ※ description shows that the surface treatment of the terminal is lead free.

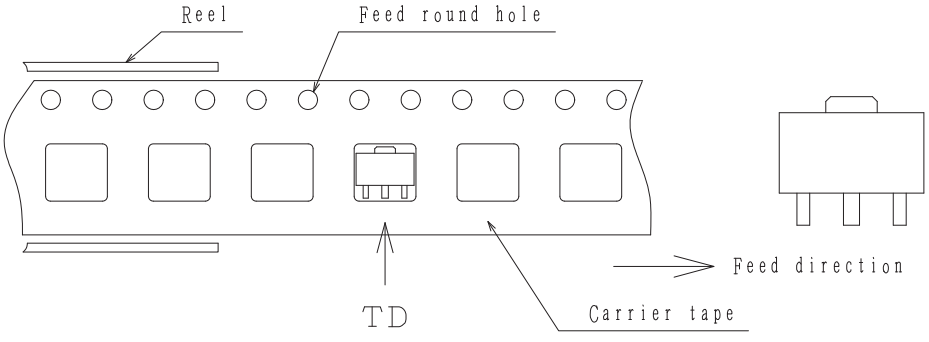
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



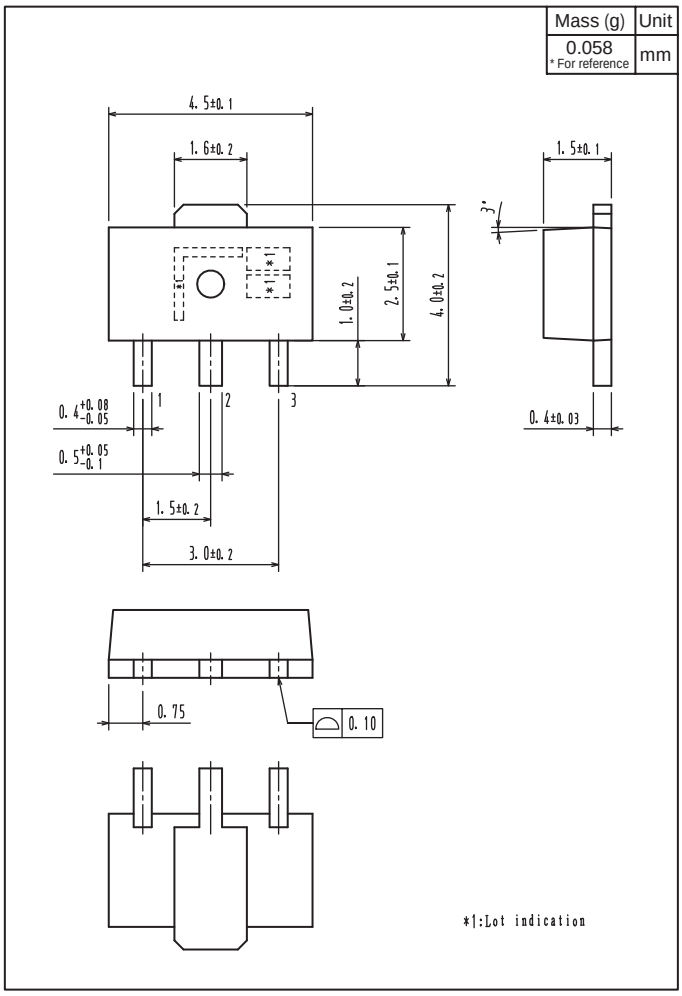
2-2. Device placement direction



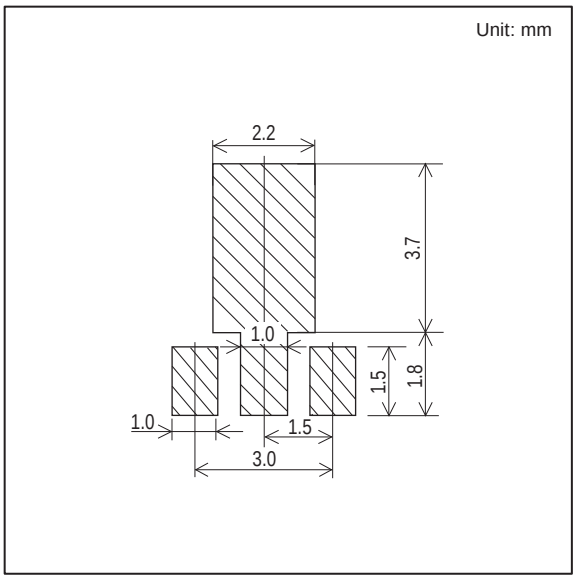
Those with pin 1 index on the feed hole side·····TD

Outline Drawing

PCP1208-TD-H



Land Pattern Example



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